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| Reg. No.: | | | | | | | |

Question Paper Code: 40982

B.E./B.Tech. DEGREE EXAMINATION, APRIL/MAY 2018

Seventh/Eighth Semester

Electrical and Electronics Engineering

EE6007 – MICRO ELECTRO MECHANICAL SYSTEMS

(Common to: Electronics and Instrumentation Engineering/Instrumentation and Control Engineering/Mechanical Engineering/Mechatronics Engineering/Robotics and Automation Engineering)

(Regulations 2013)

Time: Three Hours

Maximum: 100 Marks

Answer ALL questions

PART - A

 $(10\times2=20 \text{ Marks})$

- 1. List the intrinsic characteristics of MEMS.
- 2. What are the common methods of IC and MEMS fabrication?
- 3. Define the role of actuators and sensors in the context of MEMS.
- 4. What are the functions of interdigitated finger capacitor?
- 5. Define electromechanical coupling coefficient.
- 6. What is tactile sensor?
- 7. Define DRIE.
- 8. Compare bulk and surface micromachining.
- 9. List the features of polymers used in MEMS.
- 10. Relate factors involved in the performance of optical MEMS.

PART - B

(5×16=80 Marks)

- 11. a) i) Explain the new materials which replace the silicon material in micromachining techniques.
 - ii) Consider a piece of silicon under room temperature and thermal equilibrium. The silicon is doped with boron with a doping concentration of 10¹⁶ atoms/cm³. Find the electron and hole concentrations.

(OR)

b) i) Discuss on stress strain relationship.

(8)

(8)

(8)

ii) Write short notes on torsional deflection.

(8)

| 12. a) i | i) With suitable diagram d | emonstrate the effect of tangential force on parallel | | | | | | |
|-------------|---|--|-----------|--|--|--|--|--|
| | plate capacitor. | | (8) | | | | | |
| ii | i) Outline the use of therr | nocouple element with neat diagram. | (8) | | | | | |
| | (OR) | | | | | | | |
| b) i | Analyze the principle of t of thermal bimorph. | hermal actuators and list the various applications | (8) | | | | | |
| ii |) Derive the equilibrium | equations of single sided comb drive. | (8) | | | | | |
| 13. a) i | 3. a) i) Explain the principle of Piezo electric pressure sensor. | | | | | | | |
| ii | cantilever near the an direction. The piezoresist | sistor is embedded on the top surface of a silic chored base. The cantilever points in the <11 or is p-type doped with resistivity of 7.8 Ω cm. Find actor of the piezoresistor. | 0> | | | | | |
| | (OR) | | | | | | | |
| b)] | Discuss on stress in flexur | al cantilevers. | (16) | | | | | |
| 14. a) l | Explain the principle of pl | asma etching. | (16) | | | | | |
| | (OR) | | | | | | | |
| b) i) | Explain the LIGA proce | SS. | (8) | | | | | |
| ii) |) Compare in detail the va | arious sacrificial surface micro machining. | (8) | | | | | |
| | Discuss on the following: i) Parylene | n 1916 - Lio Strogadigarren kant van de een eleme kant Strogadigarren kant van de een elemen en ee | | | | | | |
| 1 | i) PDMS | All the Smith man of the policy of the first state of the state of | . • • • • | | | | | |
| b) F | (OR) Explain the following : | | (16) | | | | | |
| | i) Lenses i) Micro mirrors. | o diagnostico de la percenta tenedada de la digendidada Pentropera | Alto Ag | | | | | |
| | ne is, es d'Addinger Annana le laine man decresse d'oran au l'action de la comp | os vejas a aros s airos pro befora, de capalente (c | 4 | | | | | |